

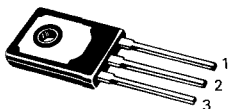
ALPHANUMERIC INDEX — CROSS-REFERENCE (Continued)

Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number	Industry Part Number	Motorola Direct Replacement	Motorola Similar Replacement	Page Number
MJE202	MJE210	MJE3055	3-904	MJE2801	MJE2801		3-902
MJE2020		TIP41	3-1083	MJE2801K		MJE2801 T	3-902
MJE2021		TIP41A	3-1083	MJE2801T	MJE2801T		3-902
MJE203		MJE3055	3-904	MJE29		TIP29	3-1071
MJE204		MJE3055	3-904	MJE2901	MJE2901		3-902
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MJE2050		MJE200	3-866	MJE2901T		MJE2955T	3-904
MJE2055		MJE3055	3-904	MJE2955	MJE2955		3-904
MJE205K		TIP41A	3-1083	MJE2955K		MJE2955T	3-904
MJE2090		TIP125	3-1098	MJE2955T	MJE2955T		3-904
MJE2091		TIP125	3-1098	MJE29A		TIP29A	3-1071
MJE2092		TIP126	3-1098	MJE29B		TIP29B	3-1071
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MJE210			3-866	MJE30		TIP30	3-1071
MJE2100		TIP120	3-1098	MJE3055	MJE3055		3-904
MJE2101		TIP120	3-1098	MJE3055K		MJE3055T	3-904
MJE2102		TIP121	3-1098	MJE3055T	MJE3055T		3-904
MJE2103		TIP121	3-1098	MJE30A		TIP30A	3-1071
MJE2150		MJE210	3-866	MJE30B		TIP30B	3-1071
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MJE231		MJE171	3-862	MJE32C		TIP32C	3-1073
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MJE234		MJE172	3-862	MJE3301		2N6038	3-135
MJE235		MJE172	3-862	MJE3302		2N6039	3-135
MJE2360		MJE2360T	3-900	MJE3310		2N6034	3-135
MJE2360T			3-900	MJE3311		2N6035	3-135
MJE2361		MJE2361T	3-900	MJE3312		2N6036	3-135
MJE2361T			3-900	MJE3370		MJE3370	3-882
MJE2370		TIP32	3-1073	MJE3371		2N5193	3-89
MJE2371		TIP32A	3-1073	MJE33A		TIP41A	3-1083
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MJE244			3-870	MJE340K		TIP48	3-1087
MJE2480		TIP31	3-1073	MJE341	MJE341		3-878
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MJE2482		2N6121	3-154	MJE3439			3-908
MJE2483		2N6122	3-154	MJE344	MJE3439		3-878
MJE2490		TIP32	3-1073	MJE3440	MJE3440		3-908
MJE2491		TIP32A	3-1073	MJE344K		TIP47	3-1087
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MJE252			3-870	MJE34B		TIP42B	3-1083
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MJE2523		TIP31A	3-1073	MJE3521		2N5190	3-85
MJE253			3-870	MJE370	MJE370		3-882
MJE254		MJE253	3-870	MJE370K		TIP32	3-1073
MJE270			3-874	MJE371	MJE371		3-884
MJE271			3-874	MJE371K		TIP32	3-1073

*Consult Motorola if a direct replacement is necessary.

TABLE 8 — PLASTIC TO-225 Type (Formerly TO-127 Type)†

STYLE 2:
PIN 1. EMITTER
2. COLLECTOR
3. BASE



CASE 90-05 (TO-225AB)

I _C Cont Amps Max	V _{CEO(sus)} Volts Min	Device Type		h _{FE} Min/Max	@ I _C Amp	Resistive Switching			f _T MHz Min	P _D (Case) Watts @ 25°C
						t _s μs Max	t _f μs Max	@ I _C Amp		
		NPN	PNP							
5	50		MJE105	25/100	2					65
	60	MJE1100## MJE1101##	MJE1090##	750 min 750 min	3A 4A				1 1	70 70
	80	MJE1102## MJE1103##	MJE1092## MJE1093##	750 min 750 min	3A 4A				1 1	70 70
8	60	MJE6043##	MJE6040##	1k/20k	4	1.5 typ	1.5 typ	4	4#	75
	80	MJE6044##	MJE6041##	1k/20k	4	1.5 typ	1.5 typ	4	4#	75
	100	MJE6045##		1k/20k	4	1.5 typ	1.5 typ	4	4#	75
10	60	MJE2801 MJE3055	MJE2901 MJE2955	25/100 20/70	3 4				2	90 90
	40	2N5989		20/120	6	0.5 typ	0.25 typ	6	2	100
12	80	2N5991		20/120	6	0.5 typ	0.25 typ	6	2	100
15	40	MJE1660		20/100	5				3	90
	60	MJE1661		20/100	5				3	90

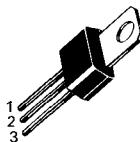
|h_{FE}| @ 1 MHz, ## Darlington

† Not recommended for new designs (check TO-220, Table 5 for alternates)

2

TABLE 9 — PLASTIC CASE 152†

STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR



(COLLECTOR CONNECTED TO TAB)

I _C Cont Amps Max	V _{CE0(sus)} Volts Min	Device Type		h _{FE} Min/Max	@ I _C Amp	Resistive Switching			f _T MHz Min	P _D (Case) Watts @ 25°C
						t _s μs Max	t _f μs Max	@ I _C Amp		
		NPN	PNP							
0.5	300	MPS-U10	MPS-U60	30 min	0.03				60	10
0.8	40	MPS-U02	MPS-U52	30 min	0.5				150	10
1	120	MPS-U03		40 min	0.01				100	10
	180	MPS-U04		40 min	0.01				100	10
2	30	MPS-U01	MPS-U51	50 min	1				50	10
	40	MPS-U01A MPS-U45##	MPS-U51A MPS-U95##	50 min 4k min	1 1				50 100	10 10

Darlington

(continued)

† Not recommended for new designs (check TO-225, Table 7 or TO-220, Table 5 for alternates)

MOTOROLA SEMICONDUCTOR TECHNICAL DATA

PNP
MJE2955, MJE2955T
NPN
MJE3055, MJE3055T

COMPLEMENTARY SILICON PLASTIC POWER TRANSISTORS

... designed for use in general-purpose amplifier and switching applications.

- DC Current Gain Specified to 10 Amperes
- High Current Gain — Bandwidth Product —
 $f_T = 2.0 \text{ MHz (Min) @ } I_C = 500 \text{ mA dc}$
- Choice of Packages — MJE3055, MJE2955 — TO-225AB (TO-127)
MJE3055T, MJE2955T — TO-220AB

MAXIMUM RATINGS

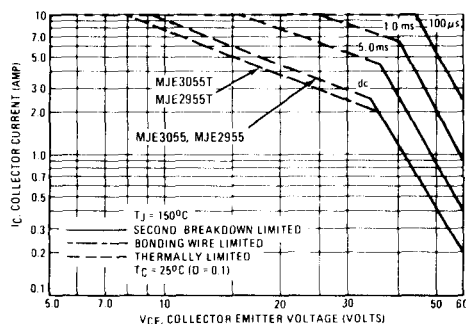
Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CE}	60	Vdc
Collector-Base Voltage	V_{CB}	70	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current	I_C	10	Adc
Base Current	I_B	6.0	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ MJE3055, MJE2955 MJE3055T, MJE2955T	P_{DT}	90 75	Watts W/ $^\circ\text{C}$
Derate above 25°C MJE3055, MJE2955 MJE3055T, MJE2955T		0.72 0.6	W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case MJE3055, MJE2955 MJE3055T, MJE2955T	θ_{JC}	1.39 1.67	$^\circ\text{C/W}$

† Safe Area Curves are indicated by Figure 1. Both limits are applicable and must be observed.

FIGURE 1 — ACTIVE REGION SAFE OPERATING AREA

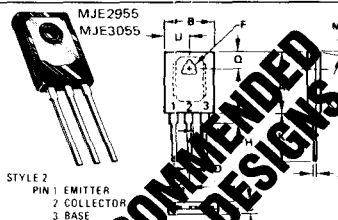


There are two limitations on the power-handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C V_{CE} limits of the transistor that must be observed for reliable operation. i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 1 is based on $T_{J(pk)} = 150^\circ\text{C}$. T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown (See A4 415A).

10 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS

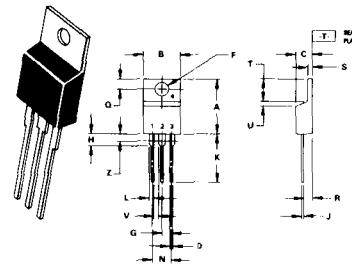
60 VOLTS
75, 90 WATTS



NOT RECOMMENDED FOR NEW DESIGNS

DIMENSIONS		INCHES	
	MIN	MAX	
A	0.16	0.20	0.635
B	0.10	0.12	0.495
C	0.05	0.07	0.125
D	0.05	0.07	0.125
E	0.05	0.07	0.125
F	0.05	0.07	0.125
G	0.05	0.07	0.125
H	0.05	0.07	0.125
I	0.05	0.07	0.125
J	0.05	0.07	0.125
K	0.05	0.07	0.125
L	0.05	0.07	0.125
M	0.05	0.07	0.125
N	0.05	0.07	0.125
O	0.05	0.07	0.125
P	0.05	0.07	0.125
Q	0.05	0.07	0.125
R	0.05	0.07	0.125
S	0.05	0.07	0.125
T	0.05	0.07	0.125
U	0.05	0.07	0.125
V	0.05	0.07	0.125

CASE 90-05
TO-225AB TYPE
(TO-127 TYPE)



DIMENSIONS		INCHES	
	MIN	MAX	
A	0.14	0.15	0.531
B	0.06	0.07	0.240
C	0.05	0.06	0.190
D	0.05	0.06	0.190
E	0.05	0.06	0.190
F	0.05	0.06	0.190
G	0.05	0.06	0.190
H	0.05	0.06	0.190
I	0.05	0.06	0.190
J	0.05	0.06	0.190
K	0.05	0.06	0.190
L	0.05	0.06	0.190
M	0.05	0.06	0.190
N	0.05	0.06	0.190
O	0.05	0.06	0.190
P	0.05	0.06	0.190
Q	0.05	0.06	0.190
R	0.05	0.06	0.190
S	0.05	0.06	0.190
T	0.05	0.06	0.190
U	0.05	0.06	0.190
V	0.05	0.06	0.190
W	0.05	0.06	0.190

STYLE 1
PIN 1 BASE
2 COLLECTOR
3 EMITTER
4 COLLECTOR

NOTES
1. DIMENSIONING AND TOLERANCING PER ANSI
2. DIM 2 DEFINES A ZONE WHERE ALL BODY AND
LEAD IRREGULARITIES ARE ALLOWED

CASE 221A-04
TO-220AB

MJE2955, MJE2955T, PNP, MJE3055, MJE3055T, NPN

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (1) ($I_C = 200 \text{ mAdc}$, $I_B = 0$)	$V_{CE(sus)}$	60	—	Vdc
Collector Cutoff Current ($V_{CE} = 30 \text{ Vdc}$, $I_B = 0$)	I_{CEO}	—	700	μAdc
Collector Cutoff Current ($V_{CE} = 70 \text{ Vdc}$, $V_{EB(off)} = 1.5 \text{ Vdc}$) ($V_{CE} = 70 \text{ Vdc}$, $V_{EB(off)} = 1.5 \text{ Vdc}$, $T_C = 150^\circ\text{C}$)	I_{CEX}	—	1.0 5.0	mAdc
Collector Cutoff Current ($V_{CB} = 70 \text{ Vdc}$, $I_E = 0$) ($V_{CB} = 70 \text{ Vdc}$, $I_E = 0$, $T_C = 150^\circ\text{C}$)	I_{CBO}	—	1.0 10	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ Vdc}$, $I_C = 0$)	I_{EBO}	—	5.0	mAdc
ON CHARACTERISTICS				
DC Current Gain (1) ($I_C = 4.0 \text{ Adc}$, $V_{CE} = 4.0 \text{ Vdc}$) ($I_C = 10 \text{ Adc}$, $V_{CE} = 4.0 \text{ Vdc}$)	h_{FE}	20 50	100 —	—
Collector-Emitter Saturation Voltage (1) ($I_C = 4.0 \text{ Adc}$, $I_B = 0.4 \text{ Adc}$) ($I_C = 10 \text{ Adc}$, $I_B = 3.3 \text{ Adc}$)	$V_{CE(sat)}$	—	1.1 8.0	Vdc
Base-Emitter On Voltage (1) ($I_C = 4.0 \text{ Adc}$, $V_{CE} = 4.0 \text{ Vdc}$)	$V_{BE(on)}$	—	1.8	Vdc
DYNAMIC CHARACTERISTICS				
Current-Gain-Bandwidth Product ($I_C = 500 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, $f = 500 \text{ kHz}$)	f_T	2.0	—	MHz

(1) Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

FIGURE 2 — DC CURRENT GAIN

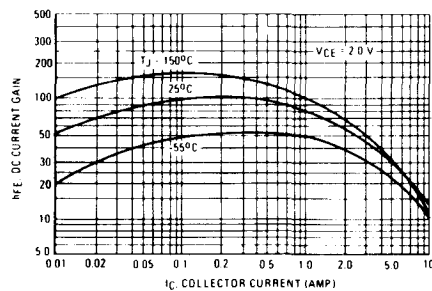
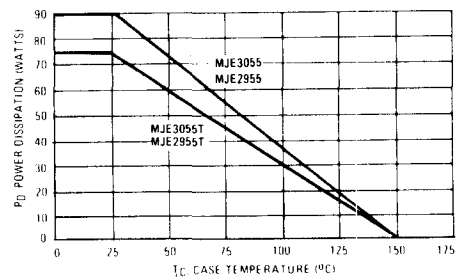
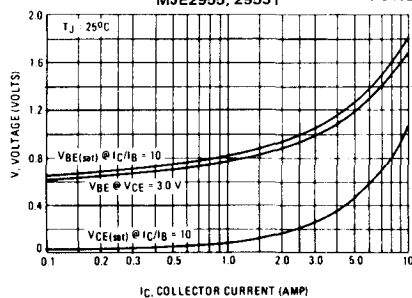


FIGURE 3 — POWER DERATING



MJE2955, 2955T

FIGURE 4 — "ON" VOLTAGES



MJE3055, 3055T

